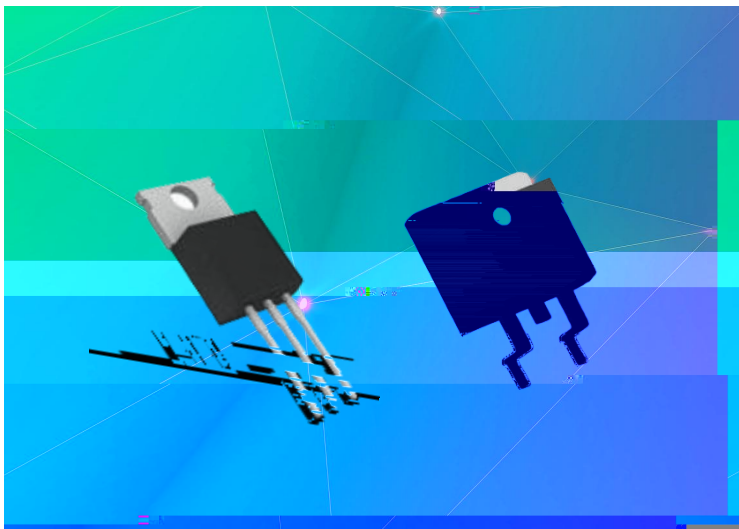


微沟



TO-220/TO-263

650V IGBT

1.

650V

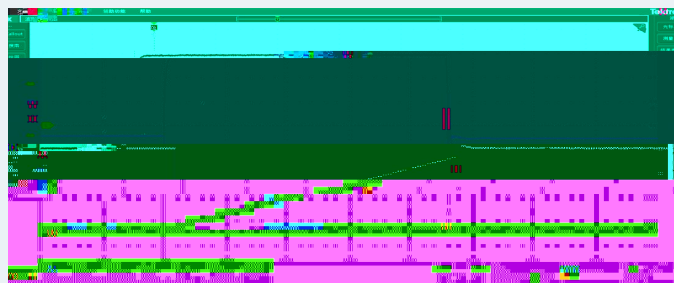
50A @ $T_c = 100$

3.

4.

I_{cm}

300A



Product Name	V_{CES} (V)	I_c (A)	$V_{GE(th)}$ (V)	$V_{CE(sat)}$ (V)	V_F (V)	P_d (W)	T_j
DGP50N 65ATS2A	650V	50A	4.8	1.4	-	283	-40~175
DGB50N 65ATS2A	650V	50A	4.8	1.4	-	283	-40~175



deductive

1. Micro-trench process platform, a highly cost- h highly

New Product Announcement